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SPECIFICATION

SEMICONDUCTOR PACKAGE CONNECTING METHOD, SEMICONDUCTOR PACKAGE CONNECTING WIRES AND SEMICONDUCTOR DEVICES

BACKGROUND OF THE INVENTION

Field of the Invention

The present invention relates to a semiconductor package connecting method and, more specifically, to a method of connecting a semiconductor package, such as a semiconductor chip, to a substrate by a wireless bonding process, particularly, a flip chip bonding process or a tape carrier bonding process, connecting wires for such a purpose, and semiconductor devices fabricated by a process employing such a connecting method.

Description of the Prior Art

A semiconductor package connecting method using bumps formed by a wire bonder and connecting materials for such a semiconductor package connecting method are disclosed in Japanese Patent Laid-open No. 63-301535. This known semiconductor package connecting method uses a fine alloy wire produced by quench solidifying an alloy containing Pb, Sn or In as a principal element. The tip of the alloy wire is heated to form a ball, the ball is attached to the wiring line of a semiconductor package or a substrate, and then the alloy wire is pulled off the ball to form a bump electrode on the wiring line. The semiconductor package and the substrate are connected by means of such bump electrodes.

Recently, aluminum alloys, such as Al-Si and Al-Cu-Si, have become used widely as wiring materials for semiconductor chips for their capability of suppressing electromigration and of improving the reliability of semiconductor chips. In attaching the ball directly to the aluminum alloy wiring line of a semiconductor package of a substrate by this known semiconductor package connecting method, the aluminum alloy wiring line must be heated in a flux containing $CuCl_2$, $ZnCl_2$, NH_4Cl, $SnCl_2$ or HCl to remove an oxide covering the surface of the aluminum alloy wiring line, which requires an additional process and time and increases the cost of the semiconductor device.

SUMMARY OF THE INVENTION

Accordingly, it is an object of the present invention to form a bump electrode by using an alloy wire produced by quench solidification and to bond the bump electrode directly to an aluminum alloy wiring line.

In one aspect of the present invention, a semiconductor package connecting method comprises steps of forming a ball of a Brinell hardness number of 6 (hereinafter referred to as "H_B 6") or higher by heating the tip of a fine alloy wire produced by quench solidifying an alloy containing Pb, Sn or In as a principal element, pulling the alloy wire off the ball with the ball attached to an aluminum alloy wiring line of a semiconductor package or a substrate to form a bump electrode on the aluminum alloy wiring line, and connecting the semiconductor package to the substrate with such bump electrodes.

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In another aspect of the present invention, a semiconductor package connecting material is a fine wire produced by quench solidifying an alloy containing Pb, Sn or In as a principal element, and one or some of additive elements, and capable of forming a ball of H_B of 6 or higher when its tip is heated.

Preferably, the alloy forming the fine wire contains one or some of additive elements among Be, B, C, Mg, Al, Si, P, Ca, Ti, V, Cr, Mn, Fe, Co, Ni, Cu, Zn, Ga, Ge, Se, Zr, Nb, Mo, Pd, Ag, Cd, In, Sn, Pb, Sb, Te, Ir, Pt, Au, Tl and Bi.

In a further aspect of the present invention, a semiconductor device comprises semiconductor packages electrically connected to a substrate by means of bump electrodes formed by heating the tip of a fine alloy wire produced by quench solidifying an alloy containing Pb, Sn or In as a principal element, wherein the wiring lines of the semiconductor packages or the substrate are formed of an aluminum alloy, and balls serving as the bump electrodes has a hardness of H_B 6 or higher.

Preferably, the alloy forming the fine wire consists of a principal element and one or some of additive elements among Be, B, C, Mg, Al, Si, P, Ca, Ti, V, Cr, Mn, Fe, Co, Ni, Cu, Zn, Ga, Ge, Se, Zr, Nb, Mo, Pd, Ag, Cd, In, Sn, Pb, Sb, Te, Ir, Pt, Au, Tl and Bi.

The ball of the alloy of a hardness of H_B 6 or higher destroys an oxide film of a hardness on the order of H_B 6 and covering the surface of the aluminum alloy wiring line, and the ball and the aluminum alloy wiring line are bonded metallurgically by the diffusion between the fresh ball and the fresh surface of the aluminum alloy wiring line.

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BRIEF DESCRIPTION OF THE DRAWINGS

The above and other objects, features and advantages of the present invention will become more apparent from the following description taken in connection with the accompanying drawings, in which:

Figure 1 is a longitudinal sectional view of a semiconductor device in a preferred embodiment according to the present invention;

Figures 2 to 5 are enlarged fragmentary longitudinal views showing steps of connecting a semiconductor package to a substrate; and

Figure 6 is a longitudinal sectional view of a semiconductor device in another embodiment according to the present invention.

DESCRIPTION OF THE PREFERRED EMBODIMENTS

Referring to Fig. 1, a semiconductor device A is of a so-called flip-chip mount type constructed by disposing a semiconductor chip (semiconductor package) 2 in the central area of the upper surface of a substrate 1, electrically connecting the aluminum alloy wiring lines 2a, i.e., wiring lines of an Al-Si alloy or an Al-Cu-Si alloy, of the semiconductor chip 2 to those of the wiring lines 1a, i.e., Cu lines plated with Sn or Au, arranged on the upper surface of the substrate 1 with bump contacts 3b, and sealing the semiconductor chip 2 and part of the wiring lines 1a of the substrate 1 with a protective resin 6, such as a silicone resin. The bump contacts 3b are formed previously by bonding balls 3a formed by heating the tip of an alloy wire 3, i.e., a connecting material, to the alloy wiring lines 2a of the semiconductor chip 2 through a procedure shown in Figs. 2 to 5.

The alloy wire 3 is formed of an alloy consisting of Pb, Sn or In as a principal element, and additive elements and produced by a quench solidifying process. The alloy wire 3 may contain one or some additive elements among Be, B, C, Mg, Al, Si, P, Ca, Ti, V, Cr, Mn, Fe, Co, Ni, Cu, Zn, Ga, Ge, Se, Zr, Nb, Mo, Pd, Ag, Cd, Sb, Te, Ir, Pt, Au, Tl and Bi. An alloy not containing Pb, Sn or In as the principal element may contain Pb, Sn or In as an additive element.

When quenched, many lattice defects are formed in the alloy forming the alloy wire 3, minute crystal grains develop in an unequilibrated phase to produce a forced solid solution of the component elements. When the alloy is drawn to produce the alloy wire 3, lattice defects are formed by work hardening, and the structure of the alloy is solution-hardened by the additive elements.

As shown in Fig. 2, the alloy wire 3 thus produced is passed through a capillary tube 4, and then the tip of the alloy wire 3 is heated with an electric torch 5 to form a ball 3a having a hardness of H_B 6 or higher. Then, as shown in Fig. 3, the capillary tube 4 is lowered to attach the ball 3a formed at the tip of the alloy wire 3 to the aluminum alloy wiring line 2a formed on the semiconductor chip 3. The ball 3a having a hardness of H_B 6 or higher destroys an oxide film coating the surface of the aluminum alloy wiring line 2a having a hardness on the order of H_B 12, and the ball 3a is bonded directly to the aluminum alloy wiring line 2a by the diffusion between the new surface of the ball 3a and the new surface of the aluminum alloy wiring line 2a. Subsequently, as shown in Fig. 4, the capillary 4 is raised to

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separate the ball 3a from the alloy wire 3 to leave the ball 3a as a bump contact 3b on the aluminum alloy wiring line 2a. When the tip of the alloy wire 3, namely, the ball 3a is heated, the unequilibrated phase disappears and the crystal grains grow large in the junction of the alloy wire 3 and the ball 3a to reduce the tensile strength of the junction, so that the junction yields and breaks readily when the alloy wire 3 is raised by the capillary.

Then, as shown in Fig. 5, semiconductor chip 2 is placed on the substrate 1 with the bump contacts 3b attached to the aluminum alloy wiring lines 2a in contact with the wiring lines 1a of the substrate 1, and then heat and pressure are applied to the bump contact 3b to connect electrically the aluminum alloy wiring lines 2a of the semiconductor chip 2 and the wiring lines 1a of the substrate and also to bond the semiconductor chip 2 to the substrate 1. Although the sphericity of the balls 3b can be improved by heating the balls 3b in the atmosphere of a flux of a chloride or an iodide before placing the balls 3b in contact with the wiring lines 1a of the substrate 1, the balls 3b may be attached to the wiring lines 1a without causing then to reflow.

Fig. 6 shows a semiconductor device A in another embodiment according to the present invention This semiconductor device a is of a so-called tape carrier bonding type, in which bump contacts 3b are formed on the aluminum alloy wiring lines 2a of a semiconductor chip 2, film leads 7 formed for example, by plating strips of a Cu foil with Sn or Au are bonded to the bump contacts 3b and the wiring lines 1a of a substrate 1.

In the foregoing embodiments, the aluminum alloy wiring lines 2a are formed on the semiconductor chip 2 and the balls 3a are bonded to the aluminum alloy wiring lines 2a as the bump contacts 3b. The wiring lines 1a of the substrate 1 may be formed of an aluminum alloy and the balls 3a may be bonded to the wiring lines 1a of the substrate 1 as the bump contacts 3b.

Tables 1 to 27 show the properties of alloys in comparison with those of controls in terms of the respective compositions of alloys forming alloy wires, the ball forming property of the alloy wires, the hardness of balls formed by heating the alloy wires, and the capability of bonding to the Al-Si alloy wiring lines.

The ball forming property is evaluated by the shape of a ball formed by arc discharge between the tip of a sample alloy wire passed through a ceramic capillary tube and an electrode disposed near the tip of the sample alloy wire in an argon gas atmosphere containing 5 % in volume hydrogen gas. In the tables, a circular mark indicates that the ball has satisfactory sphericity and smooth surface morphology.

Thus, the present invention has the following advantages.

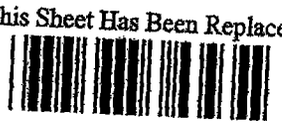
The ball of a hardness of H_B 6 or higher formed on the tip of the alloy wire produced by drawing a quench solidified alloy destroys an oxide film coating the surface of the aluminum alloy wiring line, and the ball and the aluminum alloy wiring line are bonded together metallurgically by mutual diffusion between the new surface of the aluminum alloy wiring line and the new surface of the ball, and hence the ball formed on the tip of the alloy wire can be directly joined as a bump

contact to the aluminum alloy wiring line.

Thus, the present invention enables the omission of a step of removing the oxide film coating the surface of the aluminum alloy wiring line, which reduces time and cost for assembling the semiconductor device.

Although the invention has been described in its preferred forms with a certain degree of particularity, obviously, many changes and variations are possible therein. It is therefore to be understood that the present invention may be practiced otherwise than as specifically described herein without departing from the scope and spirit thereof.

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Table 1

Composition (% by wt.)													Ball Formation	H_s	Bonding Property
Pb	Sn	In	Sb	Cu	Ni	Bi	Zn	Ag	Au	Pt	Pd	Others			
Balance	2		0.5	0.05									○	5	Bad
Balance	2		0.5	0.1									○	5	Bad
Balance	2		0.5	1.0									○	5	Bad
Balance	2		0.5	0.05					0.1				○	5	Bad
Balance	2		0.5	0.1					0.3				○	5	Bad
Balance	2		0.5	0.1					0.5				○	5	Bad
Balance	2		0.5	0.5					1.0				○	6	Good
Balance	2		0.5	1.0					1.5				○	6	Good
Balance	2		0.5	0.05						0.1			○	5	Bad
Balance	2		0.5	0.1						0.3			○	5	Bad
Balance	2		0.5	0.1						0.5			○	5	Bad
Balance	2		0.5	0.5						1.0			○	6	Good
Balance	2		0.5	1.0						1.5			○	6	Good
Balance	2		0.5	0.05							0.1		○	5	Bad
Balance	2		0.5	0.1							0.3		○	5	Bad
Balance	2		0.5	0.1							0.5		○	5	Bad
Balance	2		0.5	0.5							1.0		○	6	Good
Balance	2		0.5	1.0							1.5		○	6	Good
Balance	2		0.5		0.05				0.1				○	5	Bad
Balance	2		0.5		0.1				0.3				○	5	Bad
Balance	2		0.5		0.1				0.5				○	5	Bad
Balance	2		0.5		0.5				1.0				○	6	Good
Balance	2		0.5		1.0				1.5				○	6	Good
Balance	2		0.5		0.05					0.1			○	5	Bad
Balance	2		0.5		0.1					0.3			○	5	Bad
Balance	2		0.5		0.1					0.5			○	5	Bad
Balance	2		0.5		0.5					1.0			○	6	Good
Balance	2		0.5		1.0					1.5			○	6	Good
Balance	2		0.5		0.05						0.1		○	5	Bad
Balance	2		0.5		0.1						0.3		○	5	Bad
Balance	2		0.5		0.1						0.5		○	5	Bad
Balance	2		0.5		0.5						1.0		○	6	Good
Balance	2		0.5		1.0						1.5		○	6	Good

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Table 2

Composition (% by wt.)													Ball Formation	Hs	Bonding Property
Pb	Sn	In	Sb	Cu	Ni	Bi	Zn	Ag	Au	Pt	Pd	Others			
Balance	5		1	0.1									○	5	Bad
Balance	5		3	0.2									○	6	Good
Balance	5		5	0.5									○	6	Good
Balance	5		10	1.0									○	7	Good
Balance	5		1	0.1				1					○	5	Bad
Balance	5		3	0.2				2					○	6	Good
Balance	5		5	0.5				3					○	6	Good
Balance	5		10	1.0				5					○	7	Good
Balance	5		1		0.1								○	5	Bad
Balance	5		3		0.2								○	6	Good
Balance	5		5		0.5								○	6	Good
Balance	5		10		1.0								○	7	Good
Balance	5		1		0.1			1					○	5	Bad
Balance	5		3		0.2			2					○	6	Good
Balance	5		5		0.5			3					○	6	Good
Balance	5		10		1.0			5					○	7	Good
Balance	5			0.1		1							○	5	Bad
Balance	5			0.2		3							○	6	Good
Balance	5			0.5		5							○	6	Good
Balance	5			1.0		10							○	7	Good
Balance	5			0.1		1		1					○	5	Bad
Balance	5			0.2		3		2					○	6	Good
Balance	5			0.5		5		3					○	6	Good
Balance	5			1.0		10		5					○	7	Good
Balance	5				0.1	1							○	5	Bad
Balance	5				0.2	3							○	6	Good
Balance	5				0.5	5							○	6	Good
Balance	5				1.0	10							○	7	Good
Balance	5				0.1	1		1					○	5	Bad
Balance	5				0.2	3		2					○	6	Good
Balance	5				0.5	5		3					○	6	Good
Balance	5				1.0	10		5					○	7	Good

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Table 3

Composition (% by wt.)													Ball Formation	H_s	Bonding Property
Pb	Sn	In	Sb	Cu	Ni	Bi	Zn	Ag	Au	Pt	Pd	Others			
Balance	5		1	0.05					0.1				○	5	Bad
Balance	5		3	0.1					0.3				○	6	Good
Balance	5		5	0.1					0.5				○	6	Good
Balance	5		5	0.5					1.0				○	6	Good
Balance	5		7	0.7					1.5				○	7	Good
Balance	5		10	1.0					2.0				○	8	Good
Balance	5		1	0.05						0.1			○	5	Bad
Balance	5		3	0.1						0.3			○	6	Good
Balance	5		5	0.1						0.5			○	6	Good
Balance	5		5	0.5						1.0			○	6	Good
Balance	5		7	0.7						1.5			○	7	Good
Balance	5		10	1.0						2.0			○	8	Good
Balance	5		1	0.05							0.1		○	5	Bad
Balance	5		3	0.1							0.3		○	6	Good
Balance	5		5	0.1							0.5		○	6	Good
Balance	5		5	0.5							1.0		○	6	Good
Balance	5		7	0.7							1.5		○	7	Good
Balance	5		10	1.0							2.0		○	8	Good
Balance	5		1		0.05				0.1				○	5	Bad
Balance	5		3		0.1				0.3				○	6	Good
Balance	5		5		0.5				0.5				○	6	Good
Balance	5		7		0.7				1.5				○	7	Good
Balance	5		10		1.0				2.0				○	8	Good
Balance	5		1		0.05					0.1			○	5	Bad
Balance	5		3		0.1					0.3			○	6	Good
Balance	5		5		0.5					0.5			○	6	Good
Balance	5		7		0.7					1.5			○	7	Good
Balance	5		10		1.0					2.0			○	8	Good
Balance	5		1		0.05						0.1		○	5	Bad
Balance	5		3		0.1						0.3		○	6	Good
Balance	5		5		0.5						0.5		○	6	Good
Balance	5		7		0.7						1.5		○	7	Good
Balance	5		10		1.0						2.0		○	8	Good

Table 4

Composition (% by wt.)													Ball Formation	Hv	Bonding Property
Pb	Sn	In	Sb	Cu	Ni	Bi	Zn	Ag	Au	Pt	Pd	Others			
Balance	10		1	0.1									○	6	Good
Balance	10		3	0.5									○	7	Good
Balance	10		5	1.0									○	7	Good
Balance	10		10	1.5									○	8	Good
Balance	10		1	0.1				1					○	6	Good
Balance	10		3	0.5				2					○	7	Good
Balance	10		5	1.0				3					○	7	Good
Balance	10		10	1.5				5					○	8	Good
Balante	10		1		0.1								○	6	Good
Balance	10		3		0.5								○	7	Good
Balance	10		5		1.0								○	7	Good
Balance	10		10		1.5								○	8	Good
Balance	10		1		0.1			1					○	6	Good
Balance	10		3		0.5			2					○	7	Good
Balance	10		5		1.0			3					○	7	Good
Balance	10		10		1.5			5					○	8	Good
Balance	10			0.1		1							○	6	Good
Balance	10			0.5		3							○	7	Good
Balance	10			1.0		5							○	7	Good
Balance	10			1.5		10							○	8	Good
Balance	10			0.1		1		1					○	6	Good
Balance	10			0.5		3		2					○	7	Good
Balance	10			1.0		5		3					○	7	Good
Balance	10			1.5		10		5					○	8	Good
Balance	10				0.1	1							○	6	Good
Balance	10				0.5	3							○	7	Good
Balance	10				1.0	5							○	7	Good
Balance	10				1.5	10							○	8	Good
Balance	10				0.1	1		1					○	6	Good
Balance	10				0.5	3		2					○	7	Good
Balance	10				1.0	5		3					○	7	Good
Balance	10				1.5	10		5					○	8	Good

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Table 5

Composition (% by wt.)													Ball Formation	Hs	Bonding Property
Pb	Sn	In	Sb	Cu	Ni	Bi	Zn	Ag	Au	Pt	Pd	Others			
Balance	10		1	0.05					0.1				○	6	Good
Balance	10		3	0.1					0.3				○	7	Good
Balance	10		5	0.1					0.5				○	7	Good
Balance	10		5	0.5					1.0				○	7	Good
Balance	10		7	1.0					1.5				○	8	Good
Balance	10		10	1.5					2.0				○	8	Good
Balance	10		1	0.05						0.1			○	6	Good
Balance	10		3	0.1						0.3			○	7	Good
Balance	10		5	0.1						0.5			○	7	Good
Balance	10		5	0.5						1.0			○	7	Good
Balance	10		7	1.0						1.5			○	8	Good
Balance	10		10	1.5						2.0			○	8	Good
Balance	10		1	0.05							0.1		○	6	Good
Balance	10		3	0.1							0.3		○	7	Good
Balance	10		5	0.1							0.5		○	7	Good
Balance	10		5	0.5							1.0		○	7	Good
Balance	10		7	1.0							1.5		○	8	Good
Balance	10		10	1.5							2.0		○	8	Good
Balance	10		1		0.05				0.1				○	6	Good
Balance	10		3		0.1				0.3				○	7	Good
Balance	10		5		0.5				0.5				○	7	Good
Balance	10		7		1.0				1.5				○	8	Good
Balance	10		10		1.5				2.0				○	8	Good
Balance	10		1		0.05					0.1			○	6	Good
Balance	10		3		0.1					0.3			⊙	7	Good
Balance	10		5		0.5					0.5			○	7	Good
Balance	10		7		1.0					1.5			○	8	Good
Balance	10		10		1.5					2.0			○	8	Good
Balance	10		1		0.05						0.1		○	6	Good
Balance	10		3		0.1						0.3		○	7	Good
Balance	10		5		0.5						0.5		○	7	Good
Balance	10		7		1.0						1.5		○	8	Good
Balance	10		10		1.5						2.0		○	8	Good

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Table 6

Composition (% by wt.)													Ball Formation	Hs	Bonding Property
Pb	Sn	In	Sb	Cu	Ni	Bi	Zn	Ag	Au	Pt	Pd	Others			
Balance	30		1	0.1									○	7	Good
Balance	30		3	0.5									○	8	Good
Balance	30		5	1.0									○	8	Good
Balance	30		10	1.5									○	9	Good
Balance	30		1	0.1				1					○	7	Good
Balance	30		3	0.5				2					○	8	Good
Balance	30		5	1.0				3					○	8	Good
Balance	30		10	1.5				5					○	9	Good
Balance	30		1		0.1								○	7	Good
Balance	30		3		0.5								○	8	Good
Balance	30		5		1.0								○	8	Good
Balance	30		10		1.5								○	9	Good
Balance	30		1		0.1			1					○	7	Good
Balance	30		3		0.5			2					○	8	Good
Balance	30		5		1.0			3					○	8	Good
Balance	30		10		1.5			5					○	9	Good
Balance	30			0.1		1							○	7	Good
Balance	30			0.5		2							○	8	Good
Balance	30			0.7		5							○	8	Good
Balance	30			1.0		7							○	9	Good
Balance	30			1.5		10							○	10	Good
Balance	30			0.1		1		1					○	7	Good
Balance	30			0.5		2		2					○	8	Good
Balance	30			1.0		5		3					○	8	Good
Balance	30			1.5		10		5					○	9	Good
Balance	30		1				0.05						○	7	Good
Balance	30		3				0.1						○	8	Good
Balance	30		5				1.0						○	8	Good
Balance	30		10				3.0						○	9	Good
Balance	30		1				0.05	1					○	7	Good
Balance	30		3				0.1	2					○	8	Good
Balance	30		5				1.0	3					○	8	Good
Balance	30		10				3.0	5					○	9	Good

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Table 7

Composition (% by wt.)													Ball Formation	Hs	Bonding Property
Pb	Sn	In	Sb	Cu	Ni	Bi	Zn	Ag	Au	Pt	Pd	Others			
Balance	30		1	0.05					0.1				○	7	Good
Balance	30		3	0.1					0.3				○	8	Good
Balance	30		5	0.1					0.5				○	8	Good
Balance	30		5	0.5					1.0				○	8	Good
Balance	30		7	1.0					1.5				○	9	Good
Balance	30		10	1.5					2.0				○	10	Good
Balance	30		1	0.05						0.1			○	7	Good
Balance	30		3	0.1						0.3			○	8	Good
Balance	30		5	0.1						0.5			○	8	Good
Balance	30		5	0.5						1.0			○	8	Good
Balance	30		7	1.0						1.5			○	9	Good
Balance	30		10	1.5						2.0			○	10	Good
Balance	30		1	0.05							0.1		○	7	Good
Balance	30		3	0.1							0.3		○	8	Good
Balance	30		5	0.1							0.5		○	8	Good
Balance	30		5	0.5							1.0		○	8	Good
Balance	30		7	1.0							1.5		○	9	Good
Balance	30		10	1.5							2.0		○	10	Good
Balance	30		1		0.05				0.1				○	7	Good
Balance	30		3		0.1				0.3				○	8	Good
Balance	30		5		0.5				0.5				○	8	Good
Balance	30		7		1.0				1.5				○	9	Good
Balance	30		10		1.5				2.0				○	10	Good
Balance	30		1		0.05					0.1			○	7	Good
Balance	30		3		0.1					0.3			○	8	Good
Balance	30		5		0.5					0.5			○	8	Good
Balance	30		7		1.0					1.5			○	9	Good
Balance	30		10		1.5					2.0			○	10	Good
Balance	30		1		0.05						0.1		○	7	Good
Balance	30		3		0.1						0.3		○	8	Good
Balance	30		5		0.5						0.5		○	8	Good
Balance	30		7		1.0						1.5		○	9	Good
Balance	30		10		1.5						2.0		○	10	Good

This Sheet Has Been Replaced

THIS SHEET HAS BEEN REPLACED

Table 8

Composition (% by wt.)													Ball Formation	Hs	Bonding Property
Pb	Sn	In	Sb	Cu	Ni	Bi	Zn	Ag	Au	Pt	Pd	Others			
Balance	40		1	0.1									○	8	Good
Balance	40		3	0.5									○	9	Good
Balance	40		5	1.0									○	9	Good
Balance	40		10	1.5									○	10	Good
Balance	40		1	0.1				1					○	8	Good
Balance	40		3	0.5				2					○	9	Good
Balance	40		5	1.0				3					○	9	Good
Balance	40		10	1.5				5					○	10	Good
Balance	40		1		0.1								○	8	Good
Balance	40		3		0.5								○	9	Good
Balance	40		5		1.0								○	9	Good
Balance	40		10		1.5								○	10	Good
Balance	40		1		0.1			1					○	8	Good
Balance	40		3		0.5			2					○	9	Good
Balance	40		5		1.0			3					○	9	Good
Balance	40		10		1.5			5					○	10	Good
Balance	40			0.1		1							○	8	Good
Balance	40			0.5		2							○	9	Good
Balance	40			0.7		5							○	9	Good
Balance	40			1.0		7							○	9	Good
Balance	40			1.5		10							○	10	Good
Balance	40			0.1		1		1					○	8	Good
Balance	40			0.5		2		2					○	9	Good
Balance	40			1.0		5		3					○	9	Good
Balance	40			1.5		10		5					○	10	Good
Balance	40		1				0.05						○	8	Good
Balance	40		3				0.1						○	9	Good
Balance	40		5				1.0						○	9	Good
Balance	40		10				3.0						○	10	Good
Balance	40		1				0.05	1					○	8	Good
Balance	40		3				0.1	2					○	9	Good
Balance	40		5				1.0	3					○	9	Good
Balance	40		10				3.0	5					○	10	Good

THIS SHEET HAS BEEN REPLACED

This Sheet Has Been Replaced

Table 9

Composition (% by wt.)													Ball Formation	Hs	Bonding Property
Pb	Sn	In	Sb	Cu	Ni	Bi	Zn	Ag	Au	Pt	Pd	Others			
Balance	40		1	0.05					0.1				○	8	Good
Balance	40		3	0.1					0.3				○	9	Good
Balance	40		5	0.1					0.5				○	9	Good
Balance	40		5	0.5					1.0				○	9	Good
Balance	40		7	1.0					1.5				○	9	Good
Balance	40		10	1.5					2.0				○	10	Good
Balance	40		1	0.05						0.1			○	8	Good
Balance	40		3	0.1						0.3			○	9	Good
Balance	40		5	0.1						0.5			○	9	Good
Balance	40		5	0.5						1.0			○	9	Good
Balance	40		7	1.0						1.5			○	9	Good
Balance	40		10	1.5						2.0			○	10	Good
Balance	40		1	0.05							0.1		○	8	Good
Balance	40		3	0.1							0.3		○	9	Good
Balance	40		5	0.1							0.5		○	9	Good
Balance	40		5	0.5							1.0		○	9	Good
Balance	40		7	1.0							1.5		○	9	Good
Balance	40		10	1.5							2.0		○	10	Good
Balance	40		1		0.05				0.1				○	8	Good
Balance	40		3		0.1				0.3				○	9	Good
Balance	40		5		0.5				0.5				○	9	Good
Balance	40		7		1.0				1.5				○	9	Good
Balance	40		10		1.5				2.0				○	10	Good
Balance	40		1		0.05					0.1			○	8	Good
Balance	40		3		0.1					0.3			○	9	Good
Balance	40		5		0.5					0.5			○	9	Good
Balance	40		7		1.0					1.5			○	9	Good
Balance	40		10		1.5					2.0			○	10	Good
Balance	40		1		0.05						0.1		○	8	Good
Balance	40		3		0.1						0.3		○	9	Good
Balance	40		5		0.5						0.5		○	9	Good
Balance	40		7		1.0						1.5		○	9	Good
Balance	40		10		1.5						2.0		○	10	Good

THIS SHEET HAS BEEN RERLACED

This Sheet Has Been Replaced

Table 10

Composition (% by wt.)													Ball Formation	Hs	Bonding Property
Pb	Sn	In	Sb	Cu	Ni	Bi	Zn	Ag	Au	Pt	Pd	Others			
Balance	50		1	0.1									○	10	Good
Balance	50		3	0.5									○	10	Good
Balance	50		5	1.0									○	11	Good
Balance	50		10	1.5									○	11	Good
Balance	50		1	0.1				1					○	10	Good
Balance	50		3	0.5				2					○	10	Good
Balance	50		5	1.0				3					○	11	Good
Balance	50		10	1.5				5					○	11	Good
Balance	50		1		0.1								○	10	Good
Balance	50		3		0.5								○	10	Good
Balance	50		5		1.0								○	11	Good
Balance	50		10		1.5								○	11	Good
Balance	50		1		0.1			1					○	10	Good
Balance	50		3		0.5			2					○	10	Good
Balance	50		5		1.0			3					○	11	Good
Balance	50		10		1.5			5					○	11	Good
Balance	50			0.1		1							○	10	Good
Balance	50			0.5		2							○	10	Good
Balance	50			0.7		5							○	10	Good
Balance	50			1.0		7							○	11	Good
Balance	50			1.5		10							○	11	Good
Balance	50			0.1		1		1					○	10	Good
Balance	50			0.5		2		2					○	10	Good
Balance	50			1.0		5		3					○	11	Good
Balance	50			1.5		10		5					○	11	Good
Balance	50		1				0.05						○	10	Good
Balance	50		3				0.1						○	10	Good
Balance	50		5				1.0						○	11	Good
Balance	50		10				3.0						○	11	Good
Balance	50		1				0.05	1					○	10	Good
Balance	50		3				0.1	2					○	10	Good
Balance	50		5				1.0	3					○	11	Good
Balance	50		10				3.0	5					○	11	Good

THIS SHEET HAS BEEN REPLACED

This Sheet Has Been Replaced

Table 11

Composition (% by wt.)													Ball Formation	H_s	Bonding Property
Pb	Sn	In	Sb	Cu	Ni	Bi	Zn	Ag	Au	Pt	Pd	Others			
Balance	50		1	0.05					0.1				○	10	Good
Balance	50		3	0.1					0.3				○	10	Good
Balance	50		5	0.1					0.5				○	11	Good
Balance	50		5	0.5					1.0				○	11	Good
Balance	50		7	1.0					1.5				○	11	Good
Balance	50		10	1.5					2.0				○	11	Good
Balance	50		1	0.05						0.1			○	10	Good
Balance	50		3	0.1						0.3			○	10	Good
Balance	50		5	0.1						0.5			○	11	Good
Balance	50		5	0.5						1.0			○	11	Good
Balance	50		7	1.0						1.5			○	11	Good
Balance	50		10	1.5						2.0			○	11	Good
Balance	50		1	0.05							0.1		○	10	Good
Balance	50		3	0.1							0.3		○	10	Good
Balance	50		5	0.1							0.5		○	11	Good
Balance	50		5	0.5							1.0		○	11	Good
Balance	50		7	1.0							1.5		○	11	Good
Balance	50		10	1.5							2.0		○	11	Good
Balance	50		1		0.05				0.1				○	10	Good
Balance	50		3		0.1				0.3				○	10	Good
Balance	50		5		0.5				0.5				○	11	Good
Balance	50		7		1.0				1.5				○	11	Good
Balance	50		10		1.5				2.0				○	11	Good
Balance	50		1		0.05					0.1			○	10	Good
Balance	50		3		0.1					0.3			○	10	Good
Balance	50		5		0.5					0.5			○	11	Good
Balance	50		7		1.0					1.5			○	11	Good
Balance	50		10		1.5					2.0			○	11	Good
Balance	50		1		0.05						0.1		○	10	Good
Balance	50		3		0.1						0.3		○	10	Good
Balance	50		5		0.5						0.5		○	11	Good
Balance	50		7		1.0						1.5		○	11	Good
Balance	50		10		1.5						2.0		○	11	Good

THIS SHEET HAS BEEN REPLACED

Table 12

Composition (% by wt.)													Ball Formation	Hs	Bonding Property
Pb	Sn	In	Sb	Cu	Ni	Bi	Zn	Ag	Au	Pt	Pd	Others			
40	Balance		1	0.1									○	10	Good
40	Balance		3	0.5									○	10	Good
40	Balance		5	1.0									○	11	Good
40	Balance		10	1.5									○	12	Good
40	Balance		1	0.1				1					○	10	Good
40	Balance		3	0.5				2					○	10	Good
40	Balance		5	1.0				3					○	11	Good
40	Balance		10	1.5				5					○	12	Good
40	Balance		1		0.1								○	10	Good
40	Balance		3		0.5								○	10	Good
40	Balance		5		1.0								○	11	Good
40	Balance		10		1.5								○	12	Good
40	Balance		1		0.1			1					○	10	Good
40	Balance		3		0.5			2					○	10	Good
40	Balance		5		1.0			3					○	11	Good
40	Balance		10		1.5			5					○	12	Good
40	Balance			0.1		1							○	10	Good
40	Balance			0.5		2							○	10	Good
40	Balance			0.7		5							○	11	Good
40	Balance			1.0		7							○	11	Good
40	Balance			1.5		10							○	12	Good
40	Balance			0.1		1		1					○	10	Good
40	Balance			0.5		2		2					○	10	Good
40	Balance			1.0		5		3					○	11	Good
40	Balance			1.5		10		5					○	12	Good
40	Balance		1				0.05						○	10	Good
40	Balance		3				0.1						○	10	Good
40	Balance		5				1.0						○	11	Good
40	Balance		10				3.0						○	12	Good
40	Balance		1				0.05	1					○	10	Good
40	Balance		3				0.1	2					○	10	Good
40	Balance		5				1.0	3					○	11	Good
40	Balance		10				3.0	5					○	12	Good

THIS SHEET HAS BEEN REPLACED

This Sheet Has Been Replaced

Table 13

Composition (% by wt.)													Ball Formation	Hs	Bonding Property
Pb	Sn	In	Sb	Cu	Ni	Bi	Zn	Ag	Au	Pt	Pd	Others			
40	Balance		1	0.05					0.1				○	10	Good
40	Balance		3	0.1					0.3				○	10	Good
40	Balance		5	0.1					0.5				○	11	Good
40	Balance		5	0.5					1.0				○	11	Good
40	Balance		7	1.0					1.5				○	12	Good
40	Balance		10	1.5					2.0				○	12	Good
40	Balance		1	0.05						0.1			○	10	Good
40	Balance		3	0.1						0.3			○	10	Good
40	Balance		5	0.1						0.5			○	11	Good
40	Balance		5	0.5						1.0			○	11	Good
40	Balance		7	1.0						1.5			○	12	Good
40	Balance		10	1.5						2.0			○	12	Good
40	Balance		1	0.05							0.1		○	10	Good
40	Balance		3	0.1							0.3		○	10	Good
40	Balance		5	0.1							0.5		○	11	Good
40	Balance		5	0.5							1.0		○	11	Good
40	Balance		7	1.0							1.5		○	12	Good
40	Balance		10	1.5							2.0		○	12	Good
40	Balance		1		0.05				0.1				○	10	Good
40	Balance		3		0.1				0.3				○	10	Good
40	Balance		5		0.5				0.5				○	11	Good
40	Balance		7		1.0				1.5				○	12	Good
40	Balance		10		1.5				2.0				○	12	Good
40	Balance		1		0.05					0.1			○	10	Good
40	Balance		3		0.1					0.3			○	10	Good
40	Balance		5		0.5					0.5			○	11	Good
40	Balance		7		1.0					1.5			○	12	Good
40	Balance		10		1.5					2.0			○	12	Good
40	Balance		1		0.05						0.1		○	10	Good
40	Balance		3		0.1						0.3		○	10	Good
40	Balance		5		0.5						0.5		○	11	Good
40	Balance		7		1.0						1.5		○	12	Good
40	Balance		10		1.5						2.0		○	12	Good

THIS SHEET HAS BEEN REPLACED

This Sheet Has Been Replaced

Table 14

Composition (% by wt.)													Ball Formation	Hs	Bonding Property
Pb	Sn	In	Sb	Cu	Ni	Bi	Zn	Ag	Au	Pt	Pd	Others			
Balance	2		0.1	0.01	0.01								○	5	Bad
Balance	2		0.5	0.03	0.03								○	5	Bad
Balance	2		0.5	0.05	0.05								○	6	Good
Balance	2		0.5	0.07	0.03								○	6	Good
Balance	2		0.5	0.03	0.07								○	6	Good
Balance	2		1.0	0.5	0.5								○	7	Good
Balance	2		0.5	0.01	0.01			0.01					○	5	Bad
Balance	2		0.5	0.03	0.03			0.05					○	5	Bad
Balance	2		0.5	0.05	0.05			0.1					○	6	Good
Balance	2		0.5	0.5	0.5			4.0					○	7	Good
Balance	2		0.5	0.01	0.01				0.05				○	5	Bad
Balance	2		0.5	0.05	0.05				0.5				○	6	Good
Balance	2		0.5	0.5	0.5					0.05			○	7	Good
Balance	2		0.5	0.01	0.01					0.5			○	5	Bad
Balance	2		0.5	0.05	0.05						0.05		○	6	Good
Balance	2		0.5	0.5	0.5						0.5		○	7	Good
Balance	5		0.1	0.01	0.01								○	5	Bad
Balance	5		0.5	0.03	0.07								○	6	Good
Balance	5		1.0	0.05	0.05								○	6	Good
Balance	5		3.0	0.07	0.07								○	7	Good
Balance	5		6.0	0.09	0.1								○	7	Good
Balance	5		8.0	0.5	0.5								○	7	Good
Balance	5		10.0	1.0	1.0								○	8	Good
Balance	5		0.1	0.01	0.01			1.0					○	6	Good
Balance	5		1.0	0.1	0.1			5.0					○	8	Good
Balance	5		4.0	0.4	0.4			10.0					○	9	Good
Balance	5		10.0	1.0	1.0			30.0					○	10	Good
Balance	5			0.01	0.01			0.1					○	5	Bad
Balance	5			0.03	0.07			0.5					○	6	Good
Balance	5			0.05	0.05			1.0					○	6	Good
Balance	5			0.07	0.03			2.0					○	6	Good
Balance	5			0.1	0.1			3.0					○	7	Good
Balance	5			0.2	0.2			4.0					○	7	Good

This Sheet Has Been Replaced

THIS SHEET HAS BEEN REPLACED

Table 15

Composition (% by wt.)													Ball Formation	H_s	Bonding Property
Pb	Sn	In	Sb	Cu	Ni	Bi	Zn	Ag	Au	Pt	Pd	Others			
Balance	5			1.0	1.0			8.0					○	8	Good
Balance	5		0.1	0.01	0.01				0.05				○	5	Bad
Balance	5		1.0	0.05	0.05				0.3				○	6	Good
Balance	5		10.0	0.5	0.5				0.5				○	7	Good
Balance	5		0.1	0.01	0.01				1.0				○	6	Good
Balance	5		1.0	0.1	0.1				5.0				○	8	Good
Balance	5		4.0	0.4	0.4				10.0				○	9	Good
Balance	5		10.0	1.0	1.0				30.0				○	10	Good
Balance	5		0.1	0.01	0.01					1.0			○	6	Good
Balance	5		1.0	0.1	0.1					5.0			○	8	Good
Balance	5		4.0	0.4	0.4					10.0			○	9	Good
Balance	5		10.0	1.0	1.0					30.0			○	10	Good
Balance	5		0.1	0.01	0.01						1.0		○	6	Good
Balance	5		1.0	0.1	0.1						5.0		○	8	Good
Balance	5		4.0	0.4	0.4						10.0		○	9	Good
Balance	5		10.0	1.0	1.0						30.0		○	10	Good
Balance	10			0.01	0.99			0.01					○	9	Good
Balance	10			0.05	0.10			0.1					○	6	Good
Balance	10			0.1	0.2			1.0					○	7	Good
Balance	10			0.2	0.2			2.0					○	7	Good
Balance	10			0.5	0.5			5.0					○	9	Good
Balance	10			0.99	0.01			8.0					○	9	Good
Balance	10			0.01	0.99				0.01				○	7	Good
Balance	10			0.09	0.10				0.1				○	8	Good
Balance	10			0.2	0.3				0.3				○	7	Good
Balance	10			0.99	0.01				1.0				○	8	Good
Balance	10			0.1	0.1					0.1			○	7	Good
Balance	10			0.5	0.5					1.0			○	8	Good
Balance	10			0.1	0.1						0.1		○	7	Good
Balance	10			0.5	0.5						1.0		○	8	Good
Balance	10		0.1	0.01	0.01			1.0					○	7	Good
Balance	10		1.0	0.2	0.2			5.0					○	8	Good
Balance	10		1.0	0.4	0.4			10.0					○	8	Good

THIS SHEET HAS BEEN REPLACED

This Sheet Has Been Replaced

Table 16

Composition (% by wt.)													Ball Formation	Hs	Bonding Property
Pb	Sn	In	Sb	Cu	Ni	Bi	Zn	Ag	Au	Pt	Pd	Others			
Balance	10		4.0	0.4	0.4			10.0					○	9	Good
Balance	10		10.0	1.0	1.0			30.0					○	10	Good
Balance	10		0.1	0.01	0.01				1.0				○	7	Good
Balance	10		1.0	0.2	0.2				5.0				○	8	Good
Balance	10		1.0	0.4	0.4				10.0				○	8	Good
Balance	10		4.0	0.4	0.4				10.0				○	9	Good
Balance	10		10.0	1.0	1.0				30.0				○	10	Good
Balance	10		0.1	0.01	0.01					1.0			○	7	Good
Balance	10		1.0	0.2	0.2					5.0			○	8	Good
Balance	10		1.0	0.4	0.4					10.0			○	8	Good
Balance	10		4.0	0.4	0.4					10.0			○	9	Good
Balance	10		10.0	1.0	1.0					30.0			○	10	Good
Balance	10		0.1	0.01	0.01						1.0		○	7	Good
Balance	10		1.0	0.2	0.2						5.0		○	8	Good
Balance	10		1.0	0.4	0.4						10.0		○	8	Good
Balance	10		4.0	0.4	0.4						10.0		○	9	Good
Balance	10		10.0	1.0	1.0						30.0		○	10	Good
Balance	15		0.1	0.01	0.01			1.0					○	8	Good
Balance	15		1.0	0.2	0.2			5.0					○	9	Good
Balance	15		1.0	0.4	0.4			10.0					○	9	Good
Balance	15		4.0	0.4	0.4			10.0					○	10	Good
Balance	15		10.0	1.0	1.0			30.0					○	11	Good
Balance	20		0.1	0.01	0.01			1.0					○	8	Good
Balance	20		1.0	0.2	0.2			5.0					○	9	Good
Balance	20		1.0	0.4	0.4			10.0					○	9	Good
Balance	20		4.0	0.4	0.4			10.0					○	11	Good
Balance	20		10.0	1.0	1.0			30.0					○	12	Good
Balance	20		0.1	0.01	0.01				1.0				○	8	Good
Balance	20		1.0	0.2	0.2				5.0				○	9	Good
Balance	20		1.0	0.4	0.4				10.0				○	9	Good
Balance	20		4.0	0.4	0.4				10.0				○	11	Good
Balance	20		10.0	1.0	1.0				30.0				○	12	Good
Balance	20		0.1	0.01	0.01					1.0			○	8	Good

This Sheet Has Been Replaced

THIS SHEET HAS BEEN REPLACED

Table 17

Composition (% by wt.)													Ball Formation	Hs	Bonding Property
Pb	Sn	In	Sb	Cu	Ni	Bi	Zn	Ag	Au	Pt	Pd	Others			
Balance	20		1.0	0.2	0.2					5.0			○	9	Good
Balance	20		1.0	0.4	0.4					10.0			○	9	Good
Balance	20		4.0	0.4	0.4					10.0			○	11	Good
Balance	20		10.0	1.0	1.0					30.0			○	12	Good
Balance	20		0.1	0.01	0.01						1.0		○	8	Good
Balance	20		1.0	0.2	0.2						5.0		○	9	Good
Balance	20		1.0	0.4	0.4						10.0		○	9	Good
Balance	20		4.0	0.4	0.4						10.0		○	11	Good
Balance	20		10.0	1.0	1.0						30.0		○	12	Good
Balance	30			0.01	0.99			0.1					○	7	Good
Balance	30			0.1	0.2			0.5					○	7	Good
Balance	30			0.3	0.4			1.0					○	8	Good
Balance	30			0.4	0.5			1.0					○	9	Good
Balance	30			0.4	0.3			1.0					○	9	Good
Balance	30			0.5	0.4			1.0					○	9	Good
Balance	30			0.5	0.5			5.0					○	10	Good
Balance	30			0.9	0.9			10.0					○	11	Good
Balance	30			0.1	0.1				0.01				○	7	Good
Balance	30			0.2	0.3				0.1				○	7	Good
Balance	30			0.3	0.4				0.3				○	9	Good
Balance	30			0.8	0.8				1.0				○	10	Good
Balance	30			0.1	0.1					0.1			○	7	Good
Balance	30			0.5	0.5					1.0			○	9	Good
Balance	30			0.1	0.1						0.1		○	7	Good
Balance	30			0.5	0.5						1.0		○	9	Good
Balance	40			0.01	0.99			0.1					○	10	Good
Balance	40			0.1	0.7			0.5					○	10	Good
Balance	40			0.3	0.4			3.0					○	11	Good
Balance	40			0.4	0.5			4.0					○	11	Good
Balance	40			0.4	0.3			4.0					○	11	Good
Balance	40			0.5	0.3			4.0					○	11	Good
Balance	40			0.5	0.5			4.0					○	11	Good
Balance	40			0.6	0.5			5.0					○	11	Good

THIS SHEET HAS BEEN REPLACED

This Sheet Has Been Replaced

Table 18

Composition (% by wt.)													Ball Formation	H_s	Bonding Property
Pb	Sn	In	Sb	Cu	Ni	Bi	Zn	Ag	Au	Pt	Pd	Others			
Balance	40			0.6	0.3			7.0					○	11	Good
Balance	40			0.99	0.01			8.0					○	11	Good
Balance	40		0.1	0.01	0.01			1.0					○	10	Good
Balance	40		1.0	0.1	0.1			5.0					○	10	Good
Balance	40		1.0	0.4	0.4			10.0					○	11	Good
Balance	40		4.0	0.4	0.4			10.0					○	12	Good
Balance	40		10.0	1.0	1.0			30.0					○	13	Good
Balance	60		0.1	0.01	0.01			1.0					○	11	Good
Balance	60		1.0	0.1	0.1			5.0					○	12	Good
Balance	60		1.0	0.4	0.4			10.0					○	13	Good
Balance	60		4.0	0.4	0.4			10.0					○	13	Good
Balance	60		10.0	1.0	1.0			30.0					○	14	Good
Balance	60		0.1	0.01	0.01				1.0				○	11	Good
Balance	60		1.0	0.1	0.1				5.0				○	12	Good
Balance	60		1.0	0.4	0.4				10.0				○	13	Good
Balance	60		4.0	0.4	0.4				10.0				○	13	Good
Balance	60		10.0	1.0	1.0				30.0				○	14	Good
Balance	60		0.1	0.01	0.01					1.0			○	11	Good
Balance	60		1.0	0.1	0.1					5.0			○	12	Good
Balance	60		1.0	0.4	0.4					10.0			○	13	Good
Balance	60		4.0	0.4	0.4					10.0			○	13	Good
Balance	60		10.0	1.0	1.0					30.0			○	14	Good
Balance	60		0.1	0.01	0.01						1.0		○	11	Good
Balance	60		1.0	0.1	0.1						5.0		○	12	Good
Balance	60		1.0	0.4	0.4						10.0		○	13	Good
Balance	60		4.0	0.4	0.4						10.0		○	13	Good
Balance	60		10.0	1.0	1.0						30.0		○	14	Good

THIS SHEET HAS BEEN REPLACED

This Sheet Has Been Replaced

Table 19

Composition (% by wt.)													Ball Formation	H_3	Bonding Property
Pb	Sn	In	Sb	Cu	Ni	Bi	Zn	Ag	Au	Pt	Pd	P			
40	Balance			0.1	0.1			4.0					○	10	Good
40	Balance			0.01	0.99			0.1					○	12	Good
40	Balance			0.1	0.8			0.5					○	12	Good
40	Balance			0.3	0.6			3.0					○	13	Good
40	Balance			0.4	0.5			4.0					○	13	Good
40	Balance			0.5	0.3			4.0					○	12	Good
40	Balance			0.5	0.6			4.0					○	13	Good
40	Balance			0.6	0.1			3.0					○	12	Good
40	Balance			0.6	0.4			4.0					○	12	Good
40	Balance			0.6	0.5			4.0					○	13	Good
40	Balance			0.6	0.7			7.0					○	13	Good
40	Balance			0.7	0.1			8.0					○	12	Good
40	Balance			0.99	0.01			10.0					○	12	Good
	Balance				1.0								○	12	Good
	Balance			0.1	0.9			4.0					○	14	Good
	Balance			0.4	0.6			10.0					○	14	Good
	Balance			0.5	0.5								○	13	Good
	Balance			0.7	0.3								○	13	Good
	Balance			1.0									○	12	Good
	Balance			2.0									○	12	Good
	Balance				2.0								○	12	Good
	Balance							0.01					○	10	Good
	Balance							0.1					○	10	Good
	Balance							1.0					○	12	Good
	Balance							5.0					○	12	Good
	Balance							10.0					○	13	Good
	Balance							20.0					○	15	Good
	Balance								0.01				○	10	Good
	Balance								0.1				○	10	Good
	Balance								1.0				○	12	Good
	Balance								5.0				○	12	Good
	Balance								10.0				○	13	Good
	Balance								20.0				○	15	Good

THIS SHEET HAS BEEN
REPLACED

This Sheet Has Been Replaced

Table 20

Composition (% by wt.)													Ball Formation	Hs	Bonding Property
Pb	Sn	In	Sb	Cu	Ni	Bi	Zn	Ag	Au	Pt	Pd	P			
	Balance									0.01			○	10	Good
	Balance									0.1			○	10	Good
	Balance									1.0			○	12	Good
	Balance									5.0			○	12	Good
	Balance									10.0			○	13	Good
	Balance									20.0			○	15	Good
	Balance										0.01		○	10	Good
	Balance										0.1		○	10	Good
	Balance										1.0		○	12	Good
	Balance										5.0		○	12	Good
	Balance										10.0		○	13	Good
	Balance										20.0		○	15	Good
	Balance		0.01					0.01					○	11	Good
	Balance		0.1					0.1					○	11	Good
	Balance		0.1					1.0					○	12	Good
	Balance		1.0					3.0					○	13	Good
	Balance		2.0					5.0					○	14	Good
	Balance		3.0					5.0					○	15	Good
	Balance		4.0					5.0					○	18	Good
	Balance		5.0					7.0					○	16	Good
	Balance		5.0					10.0					○	17	Good
	Balance		10.0					20.0					○	20	Good
	Balance		0.01						0.01				○	11	Good
	Balance		0.1						0.1				○	11	Good
	Balance		1.0						1.0				○	12	Good
	Balance		3.0						5.0				○	14	Good
	Balance		5.0						10.0				○	17	Good
	Balance		10.0						20.0				○	20	Good
	Balance		0.01							0.01			○	11	Good
	Balance		0.1							0.1			○	11	Good
	Balance		1.0							1.0			○	12	Good
	Balance		3.0							5.0			○	14	Good
	Balance		5.0							10.0			○	17	Good

This Sheet Has Been Replaced

THIS SHEET HAS BEEN REPLACED

Table 21

Composition (% by wt.)												Ball Formation	Hs	Bonding Property
Pb	Sn	In	Sb	Cu	Ni	Bi	Zn	Ag	Au	Pt	Pd	P			
	Balance		10.0							20.0			○	20	Good
	Balance		0.01								0.01		○	11	Good
	Balance		0.1								0.1		○	11	Good
	Balance		1.0								1.0		○	12	Good
	Balance		3.0								5.0		○	13	Good
	Balance		5.0								10.0		○	17	Good
	Balance		10.0								20.0		○	20	Good
	Balance						0.01	0.01					○	10	Good
	Balance						0.1	0.1					○	10	Good
	Balance						0.5	1.0					○	12	Good
	Balance						0.5	5.0					○	12	Good
	Balance						1.0	5.0					○	13	Good
	Balance						3.0	5.0					○	13	Good
	Balance						7.0	10.0					○	16	Good
	Balance						10.0	20.0					○	20	Good
	Balance						0.01	0.01				0.0001	○	10	Good
	Balance						0.1	1.0				0.005	○	11	Good
	Balance						0.2	5.0				0.025	○	12	Good
	Balance						3.0	10.0				0.1	○	14	Good
	Balance						0.01		0.01				○	10	Good
	Balance						1.0		1.0				○	12	Good
	Balance						3.0		5.0				○	13	Good
	Balance						10.0		20.0				○	20	Good
	Balance						0.01		0.01			0.0001	○	10	Good
	Balance						0.1		1.0			0.005	○	11	Good
	Balance						0.2		5.0			0.025	○	12	Good
	Balance						3.0		10.0			0.1	○	14	Good
	Balance						0.01			0.01			○	10	Good
	Balance						1.0			1.0			○	12	Good
	Balance						3.0			5.0			○	13	Good
	Balance						10.0			20.0			○	20	Good
	Balance						0.01			0.01		0.0001	○	10	Good
	Balance						0.1			1.0		0.005	○	11	Good

THIS SHEET HAS BEEN REPLACED

This Sheet Has Been Replaced

Table 22

Composition (% by wt.)												Ball Formation	Hs	Bonding Property
Pb	Sn	In	Sb	Cu	Ni	Bi	Zn	Ag	Au	Pt	Pd	P			
	Balance						0.2			5.0		0.025	○	12	Good
	Balance						3.0			10.0		0.1	○	14	Good
	Balance						0.01				0.01		○	10	Good
	Balance						1.0				1.0		○	12	Good
	Balance						3.0				5.0		○	13	Good
	Balance						10.0				20.0		○	20	Good
	Balance						0.01				0.01	0.0001	○	10	Good
	Balance						0.1				1.0	0.005	○	11	Good
	Balance						0.2				5.0	0.025	○	12	Good
	Balance						3.0				10.0	0.1	○	14	Good
	Balance		0.01	0.01				0.01					○	11	Good
	Balance		0.1	0.1				0.1					○	11	Good
	Balance		0.1	0.1				1.0					○	12	Good
	Balance		1.0	0.5				3.0					○	13	Good
	Balance		2.0	0.7				5.0					○	14	Good
	Balance		3.0	1.0				5.0					○	15	Good
	Balance		4.0	1.0				5.0					○	16	Good
	Balance		5.0	1.0				7.0					○	17	Good
	Balance		5.0	1.0				10.0					○	18	Good
	Balance		10.0	2.0				20.0					○	24	Good
	Balance		0.01	0.01					0.01				○	11	Good
	Balance		0.1	0.1					0.1				○	11	Good
	Balance		1.0	0.5					1.0				○	12	Good
	Balance		3.0	1.0					5.0				○	14	Good
	Balance		5.0	1.5					10.0				○	18	Good
	Balance		10.0	2.0					20.0				○	24	Good
	Balance		0.01	0.01						0.01			○	11	Good
	Balance		0.1	0.1						0.1			○	11	Good
	Balance		1.0	0.5						1.0			○	12	Good
	Balance		3.0	1.0						5.0			○	14	Good
	Balance		5.0	1.5						10.0			○	18	Good
	Balance		10.0	2.0						20.0			○	24	Good
	Balance		0.01	0.01							0.01		○	11	Good

THIS SHEET HAS BEEN REPLACED

This Sheet Has Been Replaced

Table 23

Composition (% by wt.)													Ball Formation	Hs	Bonding Property
Pb	Sn	In	Sb	Cu	Ni	Bi	Zn	Ag	Au	Pt	Pd	P			
	Balance		0.1	0.1							0.1		○	11	Good
	Balance		1.0	0.5							1.0		○	12	Good
	Balance		3.0	1.0							5.0		○	14	Good
	Balance		5.0	1.5							10.0		○	18	Good
	Balance		10.0	2.0							20.0		○	24	Good
	Balance		0.01		0.01			0.01					○	11	Good
	Balance		0.1		0.1			0.1					○	11	Good
	Balance		0.1		0.1			1.0					○	12	Good
	Balance		1.0		0.5			3.0					○	13	Good
	Balance		2.0		0.7			5.0					○	14	Good
	Balance		3.0		1.0			5.0					○	15	Good
	Balance		4.0		1.0			5.0					○	16	Good
	Balance		5.0		1.0			7.0					○	17	Good
	Balance		5.0		1.0			10.0					○	18	Good
	Balance		10.0		2.0			20.0					○	24	Good
	Balance		0.01		0.01				0.01				○	11	Good
	Balance		0.1		0.1				0.1				○	11	Good
	Balance		0.1		0.1				1.0				○	12	Good
	Balance		1.0		0.5				3.0				○	13	Good
	Balance		2.0		0.7				5.0				○	14	Good
	Balance		3.0		1.0				5.0				○	15	Good
	Balance		4.0		1.0				5.0				○	16	Good
	Balance		5.0		1.0				7.0				○	17	Good
	Balance		5.0		1.0				10.0				○	18	Good
	Balance		10.0		2.0				20.0				○	24	Good
	Balance		0.01		0.01					0.01			○	11	Good
	Balance		0.1		0.1					0.1			○	11	Good
	Balance		0.1		0.1					1.0			○	12	Good
	Balance		1.0		0.5					3.0			○	13	Good
	Balance		2.0		0.7					5.0			○	14	Good
	Balance		3.0		1.0					5.0			○	15	Good
	Balance		4.0		1.0					5.0			○	16	Good
	Balance		5.0		1.0					7.0			○	17	Good

This Sheet Has Been Replaced

THIS SHEET HAS BEEN REPLACED

Table 24

Composition (% by wt.)													Ball Formation	H_s	Bonding Property
Pb	Sn	In	Sb	Cu	Ni	Bi	Zn	Ag	Au	Pt	Pd	P			
	Balance		5.0		1.0					10.0			○	18	Good
	Balance		10.0		2.0					20.0			○	24	Good
	Balance		0.01		0.01						0.01		○	11	Good
	Balance		0.1		0.1						0.1		○	11	Good
	Balance		0.1		0.1						1.0		○	12	Good
	Balance		1.0		0.5						3.0		○	13	Good
	Balance		2.0		0.7						5.0		○	14	Good
	Balance		3.0		1.0						5.0		○	15	Good
	Balance		4.0		1.0						5.0		○	16	Good
	Balance		5.0		1.0						7.0		○	17	Good
	Balance		5.0		1.0						10.0		○	18	Good
	Balance		10.0		2.0						20.0		○	22	Good
	Balance		0.01				0.01	0.01					○	11	Good
	Balance		0.1				0.1	0.1					○	11	Good
	Balance		0.5				0.5	1.0					○	12	Good
	Balance		0.5				0.5	5.0					○	13	Good
	Balance		1.0				1.0	5.0					○	14	Good
	Balance		1.0				3.0	5.0					○	15	Good
	Balance		5.0				7.0	10.0					○	19	Good
	Balance		10.0				10.0	20.0					○	26	Good
	Balance		0.01				0.01	0.01				0.0001	○	11	Good
	Balance		0.5				0.1	1.0				0.005	○	12	Good
	Balance		1.0				0.2	5.0				0.025	○	13	Good
	Balance		5.0				3.0	10.0				0.1	○	18	Good
	Balance		0.01				0.01		0.01				○	11	Good
	Balance		0.5				1.0		1.0				○	12	Good
	Balance		5.0				3.0		5.0				○	17	Good
	Balance		10.0				10.0		20.0				○	26	Good
	Balance		0.01				0.01		0.01			0.0001	○	11	Good
	Balance		0.5				0.1		1.0			0.005	○	12	Good
	Balance		1.0				0.2		5.0			0.025	○	13	Good
	Balance		5.0				3.0		10.0			0.1	○	18	Good
	Balance		0.01				0.01			0.01			○	11	Good

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Table 25

Composition (% by wt.)													Ball Formation	H_B	Bonding Property
Pb	Sn	In	Sb	Cu	Ni	Bi	Zn	Ag	Au	Pt	Pd	P			
	Balance		0.5				1.0			1.0			○	12	Good
	Balance		5.0				3.0			5.0			○	17	Good
	Balance		10.0				10.0			20.0			○	26	Good
	Balance		0.01				0.01			0.01		0.0001	○	11	Good
	Balance		0.5				0.1			1.0		0.005	○	12	Good
	Balance		1.0				0.2			5.0		0.025	○	13	Good
	Balance		5.0				3.0			10.0		0.1	○	18	Good
	Balance		0.01				0.01				0.01		○	11	Good
	Balance		0.5				1.0				1.0		○	12	Good
	Balance		5.0				3.0				5.0		○	17	Good
	Balance		10.0				10.0				20.0		○	26	Good
	Balance		0.01				0.01				0.01	0.0001	○	11	Good
	Balance		0.5				0.1				1.0	0.005	○	12	Good
	Balance		1.0				0.2				5.0	0.025	○	13	Good
	Balance		5.0				3.0				10.0	0.1	○	18	Good
	Balance			0.01			0.01	0.01					○	11	Good
	Balance			0.5			1.0	1.0					○	12	Good
	Balance			1.0			1.0	5.0					○	14	Good
	Balance			2.0			10.0	20.0					○	24	Good
	Balance			0.01			0.01		0.01				○	11	Good
	Balance			0.5			1.0		1.0				○	12	Good
	Balance			2.0			10.0		20.0				○	24	Good
	Balance			0.01			0.01			0.01			○	11	Good
	Balance			0.5			1.0			1.0			○	12	Good
	Balance			2.0			10.0			20.0			○	24	Good
	Balance			0.01			0.01				0.01		○	11	Good
	Balance			0.5			1.0				1.0		○	12	Good
	Balance			2.0			10.0				20.0		○	24	Good
	Balance				0.01		0.01	0.01					○	11	Good
	Balance				0.5		1.0	1.0					○	12	Good
	Balance				1.0		1.0	5.0					○	14	Good
	Balance				2.0		10.0	20.0					○	24	Good
	Balance				0.01		0.01		0.01				○	11	Good

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Table 26

Composition (% by wt.)													Ball Formation	Hs	Bonding Property
Pb	Sn	In	Sb	Cu	Ni	Bi	Zn	Ag	Au	Pt	Pd	P			
	Balance				0.5		1.0		1.0				○	12	Good
	Balance				2.0		10.0		20.0				○	24	Good
	Balance				0.01		0.01			0.01			○	11	Good
	Balance				0.5		1.0			1.0			○	12	Good
	Balance				2.0		10.0			20.0			○	24	Good
	Balance				0.01		0.01				0.01		○	11	Good
	Balance				0.5		1.0				1.0		○	12	Good
	Balance				2.0		10.0				20.0		○	24	Good
	Balance		0.01	0.01			0.01	0.01					○	11	Good
	Balance		1.0	0.5			1.0	1.0					○	13	Good
	Balance		5.0	1.0			1.0	5.0					○	15	Good
	Balance		10.0	2.0			10.0	20.0					○	26	Good
	Balance		0.01	0.01			0.01		0.01				○	11	Good
	Balance		1.0	0.5			1.0		1.0				○	13	Good
	Balance		10.0	2.0			10.0		10.0				○	26	Good
	Balance		0.01	0.01			0.01			0.01			○	11	Good
	Balance		1.0	0.5			1.0			1.0			○	13	Good
	Balance		10.0	2.0			10.0			10.0			○	26	Good
	Balance		0.01	0.01			0.01				0.01		○	11	Good
	Balance		1.0	0.5			1.0				1.0		○	13	Good
	Balance		10.0	2.0			10.0				10.0		○	26	Good
	Balance		0.01		0.01		0.01	0.01					○	11	Good
	Balance		1.0		0.5		1.0	1.0					○	13	Good
	Balance		5.0		1.0		1.0	5.0					○	15	Good
	Balance		10.0		2.0		10.0	20.0					○	26	Good
	Balance		0.01		0.01		0.01		0.01				○	11	Good
	Balance		1.0		0.5		1.0		1.0				○	13	Good
	Balance		10.0		2.0		10.0		10.0				○	26	Good
	Balance		0.01		0.01		0.01			0.01			○	11	Good
	Balance		1.0		0.5		1.0			1.0			○	13	Good
	Balance		10.0		2.0		10.0			10.0			○	26	Good
	Balance		0.01		0.01		0.01				0.01		○	11	Good
	Balance		1.0	0.5			1.0				1.0		○	13	Good

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Table 27

Composition (% by wt.)													Ball Formation	H_v	Bonding Property
Pb	Sn	In	Sb	Cu	Ni	Bi	Zn	Ag	Au	Pt	Pd	P			
	Balance		10.0	2.0			10.0				10.0		○	26	Good

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What is claimed is:

1. A semiconductor package connecting method for electrically connecting a semiconductor package to a substrate, said method comprising steps of:

forming a ball having a Brinell hardness number of H_B 6 or higher by heating the tip of a fine alloy wire produced by drawing an alloy material containing Pb, Sn or In as a principal element and produced by quench solidification;

pulling the alloy wire away from a semiconductor package or a substrate after joining the ball to an aluminum alloy wiring line formed on the semiconductor package or an aluminum alloy wiring line formed on the substrate to separate the alloy wire from the ball and to leave the ball as a bump contact on the aluminum alloy wiring line of the semiconductor package or on that of the substrate; and

electrically connecting the semiconductor package to the substrate through such bump contacts.

2. A semiconductor package connecting method according to Claim 1, wherein the alloy wire is passed through a capillary tube employed in a wire bonder, and the balls are joined to the aluminum alloy wiring lines by a wire bonding method.

3. A semiconductor package connecting method according to Claim 1, wherein the alloy forming the alloy wire contains, as an additive element or additive elements one or some elements among Be, B, C, Mg, Al, Si, P, Ca, Ti, V, Cr, Mn, Fe, Co, Ni, Cu, Zn, Ga, Ge, Se, Zr, Nb, Mo, Pd, Ag, Cd, In, Sn, Pb, Sb, Te, Ir, Pt, Au and Bi.

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4. A semiconductor package connecting method according to Claim 1, wherein the Brinell hardness number of the ball is in the range of H_B 6 to H_B 26.

5. A semiconductor package connecting wire formed by drawing an alloy material produced by quench solidifying an alloy containing Pb, Sn or In as a principal element, and an additive element or additive elements, and capable of forming a ball having a hardness of Brinell hardness number 6 or higher when its tip is heated.

6. A semiconductor package connecting wire according to Claim 5, wherein the alloy contains one or some elements among Be, B, C, Mg, Al, Si, P, Ca, Ti, V, Cr, Mn, Fe, Co, Ni, Cu, Zn, Ga, Ge, Se, Zr, Nb, Mo, Pd, Ag, Cd, In, Sn, Pb, Sb, Te, Ir, Pt, Au, Tl and Bi.

7. A semiconductor package connecting wire according to Claim 5, wherein the Brinell hardness number of the ball is in the range of H_B 6 to H_B 26.

8. A semiconductor device comprising:

a substrate; and

a semiconductor package electrically connected to the substrate through a bump contacts formed by attaching balls each formed by heating the tip of a fin alloy wire formed of an alloy material produced by quench solidifying an alloy containing Pb, Sn or In as a principal element;

wherein wiring lines formed on the substrate or on the semiconductor package are formed of an aluminum alloy, and the Brinell hardness number of the balls is H_B 6 or higher.

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9. A semiconductor device according to Claim 8, wherein the alloy wire is passed through a capillary tube employed in a wire bonder, and the balls are joined to the aluminum alloy wiring lines by a wire bonding method.

10. A semiconductor device according to Claim 8, wherein the alloy material forming the alloy wire contains, as an additive element or additive elements, one or some elements among Be, B, C, Mg, Al, Si, P, Ca, Ti, V, Cr, Mn, Fe, Co, Ni, Cu, Zn, Ga, Ge, Se, Zr, Nb, Mo, Pd, Ag, Cd, In, Sn, Pb, Sb, Te, Ir, Pt, Au, Tl and Bi.

11. A semiconductor device according to Claim 8, wherein the Brinell hardness number of the ball is in the range of H_B 6 to H_B 26.

12. A semiconductor device according to Claim 8, wherein the semiconductor device is of a flip-chip mount type.

13. A semiconductor device according to Claim 8, wherein the semiconductor device is of tape carrier bonding type.

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